## **1** General description

The 74LVC1G125 provides one non-inverting buffer/line driver with 3-state output. The 3-state output is controlled by the output enable input ( $\overline{OE}$ ). A HIGH-level at pin  $\overline{OE}$  causes the output to assume a high-impedance OFF-state.

The input can be driven from either 3.3 V or 5 V devices. This feature allows the use of this device in a mixed 3.3 V and 5 V environment.

This device is fully specified for partial power-down applications using  $I_{OFF}$ . The  $I_{OFF}$  circuitry disables the output, preventing the damaging backflow current through the device when it is powered down.

## 2 Features and benefits

- Wide supply voltage range from 1.65 V to 5.5 V
- High noise immunity
- Complies with JEDEC standard:
  - JESD8-7 (1.65 V to 1.95 V)
  - JESD8-5 (2.3 V to 2.7 V)
  - JESD8-B/JESD36 (2.7 V to 3.6 V)
- ±24 mA output drive (V<sub>CC</sub> = 3.0 V)
- ESD protection:
  - HBM JESD22-A114F exceeds 2 000 V
  - MM JESD22-A115-A exceeds 200 V
- CMOS low power consumption
- Inputs accept voltages up to 5 V
- Latch-up performance exceeds 250 mA
- Direct interface with TTL levels
- Multiple package options
- Specified from -40 °C to +85 °C and -40 °C to +125 °C

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Bus buffer/line driver; 3-state

#### **Ordering information** 3

Type number	Package							
	Temperature range	Name	Description	Version				
74LVC1G125GW	-40 °C to +125 °C	TSSOP5	plastic thin shrink small outline package; 5 leads; body width 1.25 mm	SOT353-7				
74LVC1G125GV	-40 °C to +125 °C	SC-74A	plastic surface-mounted package; 5 leads	SOT753				
74LVC1G125GM	-40 °C to +125 °C	XSON6	plastic extremely thin small outline package; no leads; 6 terminals; body 1 x 1.45 x 0.5 mm	SOT886				
74LVC1G125GF	-40 °C to +125 °C	XSON6	plastic extremely thin small outline package; no leads; 6 terminals; body 1 x 1 x 0.5 mm	SOT891				
74LVC1G125GN	-40 °C to +125 °C	XSON6	extremely thin small outline package; no leads; 6 terminals; body 0.9 x 1.0 x 0.35 mm	SOT1115				
74LVC1G125GS	-40 °C to +125 °C	XSON6	extremely thin small outline package; no leads; 6 terminals; body 1.0 x 1.0 x 0.35 mm	SOT1202				
74LVC1G125GX	-40 °C to +125 °C	X2SON5	X2SON5: plastic thermal enhanced extremely thin small outline package; no leads; 5 terminals; body 0.8 x 0.8 x 0.35 mm	SOT1226				

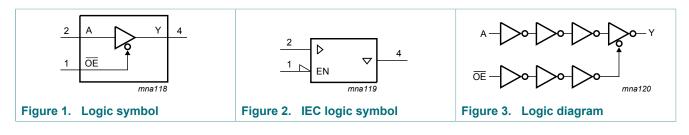
#### Marking 4

#### Table 2. Marking

Type number	Marking code <sup>[1]</sup>
74LVC1G125GW	VM
74LVC1G125GV	V25
74LVC1G125GM	VM
74LVC1G125GF	VM
74LVC1G125GN	VM
74LVC1G125GS	VM
74LVC1G125GX	VM

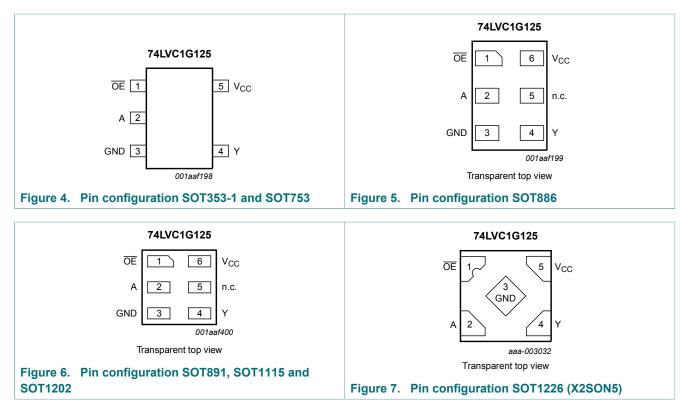
[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

#### **Functional diagram** 5



## 6 Pinning information

## 6.1 Pinning



## 6.2 Pin description

Table 3. Pin d	escription					
Symbol	Pin	Pin				
	TSSOP5, SC-74A and X2SON5	TSSOP5, SC-74A and X2SON5 XSON6				
ŌĒ	1	1	output enable input			
A	2	2	data input			
GND	3	3	ground (0 V)			
Y	4	4	data output			
n.c.	-	5	not connected			
V <sub>CC</sub>	5	6	supply voltage			

#### **Functional description** 7

#### Table 4. Function table

H = HIGH voltage level; L = LOW voltage level; X = don't care; Z = high-impedance OFF-state.

Input		Output
OE	A	Y
L	L	L
L	Н	Н
Н	X	Z

#### **Limiting values** 8

#### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>CC</sub>	supply voltage		-0.5	+6.5	V
I <sub>IK</sub>	input clamping current	V <sub>1</sub> < 0 V	-50	-	mA
VI	input voltage	[1]	-0.5	+6.5	V
I <sub>OK</sub>	output clamping current	$V_{\rm O}$ > $V_{\rm CC}$ or $V_{\rm O}$ < 0 V	-	±50	mA
Vo	output voltage	Active mode [1] [2]	-0.5	V <sub>CC</sub> + 0.5	V
		Power-down mode <sup>[1] [2]</sup>	-0.5	+6.5	V
I <sub>O</sub>	output current	$V_{O}$ = 0 V to $V_{CC}$	-	±50	mA
I <sub>CC</sub>	supply current		-	100	mA
I <sub>GND</sub>	ground current		-100	-	mA
P <sub>tot</sub>	total power dissipation	$T_{amb} = -40 \ ^{\circ}C \ to \ +125 \ ^{\circ}C$ <sup>[3]</sup>	-	250	mW
T <sub>stg</sub>	storage temperature		-65	+150	°C

The input and output voltage ratings may be exceeded if the input and output current ratings are observed.
 When V<sub>CC</sub> = 0 V (Power-down mode), the output voltage can be 5.5 V in normal operation.
 For TSSOP5 and SC-74A packages: above 87.5 °C the value of P<sub>tot</sub> derates linearly with 4.0 mW/K.

For XSON6 and X2SON5 package: above 118 °C the value of Ptot derates linearly with 7.8 mW/K.

#### **Recommended operating conditions** 9

#### Table 6. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V <sub>CC</sub>	supply voltage		1.65	-	5.5	V
VI	input voltage		0	-	5.5	V
Vo	output voltage	Active mode	0	-	V <sub>CC</sub>	V
		V <sub>CC</sub> = 0 V; Power-down mode	0	-	5.5	V
T <sub>amb</sub>	ambient temperature		-40	-	+125	°C

## Bus buffer/line driver; 3-state

Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
Δt/ΔV	input transition rise and fall rate	V <sub>CC</sub> = 1.65 V to 2.7 V	-	-	20	ns/V
		V <sub>CC</sub> = 2.7 V to 5.5 V	-	-	10	ns/V

## **10 Static characteristics**

#### Table 7. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур <sup>[1]</sup>	Max	Unit
T <sub>amb</sub> = -4	0 °C to +85 °C					
VIH	HIGH-level input voltage	V <sub>CC</sub> = 1.65 V to 1.95 V	$0.65 \times V_{CC}$	-	-	V
		V <sub>CC</sub> = 2.3 V to 2.7 V	1.7	-	-	V
		V <sub>CC</sub> = 2.7 V to 3.6 V	2.0	-	-	V
		V <sub>CC</sub> = 4.5 V to 5.5 V	$0.7 \times V_{CC}$	-	-	V
V <sub>IL</sub>	LOW-level input voltage	V <sub>CC</sub> = 1.65 V to 1.95 V	-	-	$0.35 \times V_{CC}$	V
		V <sub>CC</sub> = 2.3 V to 2.7 V	-	-	0.7	V
		V <sub>CC</sub> = 2.7 V to 3.6 V	-	-	0.8	V
		V <sub>CC</sub> = 4.5 V to 5.5 V	-	-	0.3 × V <sub>CC</sub>	V
V <sub>OL</sub>	LOW-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
		$V_{CC}$ = 1.65 V to 5.5 V; I <sub>O</sub> = 100 µA	-	-	0.1	V
		V <sub>CC</sub> = 1.65 V; I <sub>O</sub> = 4 mA	-	-	0.45	V
		V <sub>CC</sub> = 2.3 V; I <sub>O</sub> = 8 mA	-	-	0.3	V
		V <sub>CC</sub> = 2.7 V; I <sub>O</sub> = 12 mA	-	-	0.4	V
		V <sub>CC</sub> = 3.0 V; I <sub>O</sub> = 24 mA	-	-	0.55	V
		V <sub>CC</sub> = 4.5 V; I <sub>O</sub> = 32 mA	-	-	0.55	V
V <sub>OH</sub>	HIGH-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
		$V_{CC}$ = 1.65 V to 5.5 V; I <sub>O</sub> = -100 $\mu$ A	V <sub>CC</sub> - 0.1	-	-	V
		V <sub>CC</sub> = 1.65 V; I <sub>O</sub> = -4 mA	1.2	-	-	V
		V <sub>CC</sub> = 2.3 V; I <sub>O</sub> = -8 mA	1.9	-	-	V
		$V_{CC}$ = 2.7 V; I <sub>O</sub> = -12 mA	2.2	-	-	V
		V <sub>CC</sub> = 3.0 V; I <sub>O</sub> = -24 mA	2.3	-	-	V
		V <sub>CC</sub> = 4.5 V; I <sub>O</sub> = -32 mA	3.8	-	-	V
I	input leakage current	$V_{CC}$ = 0 V to 5.5 V; V <sub>I</sub> = 5.5 V or GND	-	±0.1	±1	μA
I <sub>OZ</sub>	OFF-state output current	$V_{CC}$ = 3.6 V; V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> ; V <sub>O</sub> = 5.5 V or GND	-	±0.1	±2	μA
I <sub>OFF</sub>	power-off leakage current	$V_{CC}$ = 0 V; V <sub>I</sub> or V <sub>O</sub> = 5.5 V	-	±0.1	±2	μA
I <sub>CC</sub>	supply current	V <sub>I</sub> = 5.5 V or GND; V <sub>CC</sub> = 1.65 V to 5.5 V; I <sub>O</sub> = 0 A	-	0.1	4	μA
ΔI <sub>CC</sub>	additional supply current	per pin; $V_{CC}$ = 2.3 V to 5.5 V; V <sub>I</sub> = V <sub>CC</sub> - 0.6 V; I <sub>O</sub> = 0 A	-	5	500	μA
CI	input capacitance		-	5	-	pF

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## 74LVC1G125

## Bus buffer/line driver; 3-state

Symbol	Parameter	Conditions	Min	Typ <sup>[1]</sup>	Max	Unit
T <sub>amb</sub> = -4	0 °C to +125 °C					
VIH	HIGH-level input voltage	V <sub>CC</sub> = 1.65 V to 1.95 V	0.65 × V <sub>CC</sub>	-	-	V
		V <sub>CC</sub> = 2.3 V to 2.7 V	1.7	-	-	V
		V <sub>CC</sub> = 2.7 V to 3.6 V	2.0	-	-	V
		V <sub>CC</sub> = 4.5 V to 5.5 V	$0.7 \times V_{CC}$	-	-	V
V <sub>IL</sub>	LOW-level input voltage	V <sub>CC</sub> = 1.65 V to 1.95 V	-	-	$0.35 \times V_{CC}$	V
		V <sub>CC</sub> = 2.3 V to 2.7 V	-	-	0.7	V
		V <sub>CC</sub> = 2.7 V to 3.6 V	-	-	0.8	V
		V <sub>CC</sub> = 4.5 V to 5.5 V	-	-	$0.3 \times V_{CC}$	V
V <sub>OL</sub>	LOW-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
		$V_{CC}$ = 1.65 V to 5.5 V; I <sub>O</sub> = 100 µA	-	-	0.1	V
		V <sub>CC</sub> = 1.65 V; I <sub>O</sub> = 4 mA	-	-	0.70	V
		V <sub>CC</sub> = 2.3 V; I <sub>O</sub> = 8 mA	-	-	0.45	V
		V <sub>CC</sub> = 2.7 V; I <sub>O</sub> = 12 mA	-	-	0.60	V
		V <sub>CC</sub> = 3.0 V; I <sub>O</sub> = 24 mA	-	-	0.80	V
		V <sub>CC</sub> = 4.5 V; I <sub>O</sub> = 32 mA	-	-	0.80	V
V <sub>OH</sub>	HIGH-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
		$V_{CC}$ = 1.65 V to 5.5 V; I <sub>O</sub> = -100 µA	V <sub>CC</sub> - 0.1	-	-	V
		V <sub>CC</sub> = 1.65 V; I <sub>O</sub> = -4 mA	0.95	-	-	V
		V <sub>CC</sub> = 2.3 V; I <sub>O</sub> = -8 mA	1.7	-	-	V
		V <sub>CC</sub> = 2.7 V; I <sub>O</sub> = -12 mA	1.9	-	-	V
		V <sub>CC</sub> = 3.0 V; I <sub>O</sub> = -24 mA	2.0	-	-	V
		V <sub>CC</sub> = 4.5 V; I <sub>O</sub> = -32 mA	3.4	-	-	V
l <sub>l</sub>	input leakage current	$V_{CC}$ = 0 V to 5.5 V; V <sub>I</sub> = 5.5 V or GND	-	-	±1	μA
I <sub>OZ</sub>	OFF-state output current	$V_{CC}$ = 3.6 V; V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> ; V <sub>O</sub> = 5.5 V or GND	-	-	±2	μA
I <sub>OFF</sub>	power-off leakage current	$V_{CC}$ = 0 V; V <sub>1</sub> or V <sub>0</sub> = 5.5 V	-	-	±2	μA
I <sub>CC</sub>	supply current	V <sub>I</sub> = 5.5 V or GND; V <sub>CC</sub> = 1.65 V to 5.5 V; I <sub>O</sub> = 0 A	-	-	4	μA
ΔI <sub>CC</sub>	additional supply current	per pin; $V_{CC}$ = 2.3 V to 5.5 V; V <sub>I</sub> = V <sub>CC</sub> - 0.6 V; I <sub>O</sub> = 0 A	-	-	500	μA

[1] All typical values are measured at V\_{CC} = 3.3 V and T\_{amb} = 25 °C.

### Bus buffer/line driver; 3-state

## **11 Dynamic characteristics**

#### Table 8. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V). For test circuit see Figure 10.

Symbol Parameter		Conditions	-4	0 °C to +85	°C	-40 °C to +125 °C		Unit
			Min	Typ <sup>[1]</sup>	Max	Min	Max	
t <sub>pd</sub>	propagation delay	A to Y; see <u>Figure 8</u> <sup>[2]</sup>						
		V <sub>CC</sub> = 1.65 V to 1.95 V	1.0	3.3	8.0	1.0	10.5	ns
		$V_{CC}$ = 2.3 V to 2.7 V	0.5	2.2	5.5	0.5	7	ns
		V <sub>CC</sub> = 2.7 V	0.5	2.5	5.5	0.5	7	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	0.5	2.1	4.5	0.5	6	ns
		$V_{CC}$ = 4.5 V to 5.5 V	0.5	1.7	4.0	0.5	5.5	ns
t <sub>en</sub>	enable time	OE to Y; see Figure 9 [3]						
		V <sub>CC</sub> = 1.65 V to 1.95 V	1.0	4.1	9.4	1.0	12	ns
		$V_{CC}$ = 2.3 V to 2.7 V	0.5	2.8	6.6	0.5	8.5	ns
		V <sub>CC</sub> = 2.7 V	0.5	3.3	6.6	0.5	8.5	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	0.5	2.4	5.3	0.5	7	ns
		$V_{CC}$ = 4.5 V to 5.5 V	0.5	2.1	5.0	0.5	6.5	ns
t <sub>dis</sub>	disable time	OE to Y; see Figure 9 [4]						
		V <sub>CC</sub> = 1.65 V to 1.95 V	1.0	4.3	9.2	1.0	12	ns
		$V_{CC}$ = 2.3 V to 2.7 V	0.5	2.7	5.0	0.5	6.5	ns
		V <sub>CC</sub> = 2.7 V	0.5	3.0	5.0	0.5	6.5	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	0.5	3.1	5.0	0.5	6.5	ns
		$V_{CC}$ = 4.5 V to 5.5 V	0.5	2.2	4.2	0.5	5.5	ns
C <sub>PD</sub>	power dissipation	per buffer; V <sub>I</sub> = GND to V <sub>CC</sub> <sup>[5]</sup>						
	capacitance	output enabled	-	25	-	-	-	pF
		output disabled	-	6	-	-	-	pF

[1] Typical values are measured at  $T_{amb}$  = 25 °C and  $V_{CC}$  = 1.8 V, 2.5 V, 2.7 V, 3.3 V and 5.0 V respectively.

- [1] Typical values are measured at T<sub>amb</sub> = 25 °C and V<sub>CC</sub> = 1.8 V, 2.5 V [2] t<sub>pd</sub> is the same as t<sub>PLH</sub> and t<sub>PHL</sub> [3] t<sub>en</sub> is the same as t<sub>PZH</sub> and t<sub>PZL</sub> [4] t<sub>dis</sub> is the same as t<sub>PLZ</sub> and t<sub>PHZ</sub> [5] C<sub>PD</sub> is used to determine the dynamic power dissipation (P<sub>D</sub> in  $\mu$ W). P<sub>D</sub> = C<sub>PD</sub> x V<sub>CC</sub><sup>2</sup> x f<sub>i</sub> x N +  $\Sigma$ (C<sub>L</sub> x V<sub>CC</sub><sup>2</sup> x f<sub>o</sub>) where:

 $f_i$  = input frequency in MHz;

 $f_o$  = output frequency in MHz;

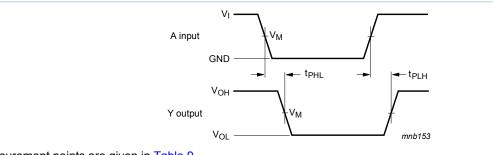
C<sub>L</sub> = output load capacitance in pF;

V<sub>CC</sub> = supply voltage in V;

N = number of inputs switching;

 $\Sigma(C_L \times V_{CC}^2 \times f_0)$  = sum of outputs.

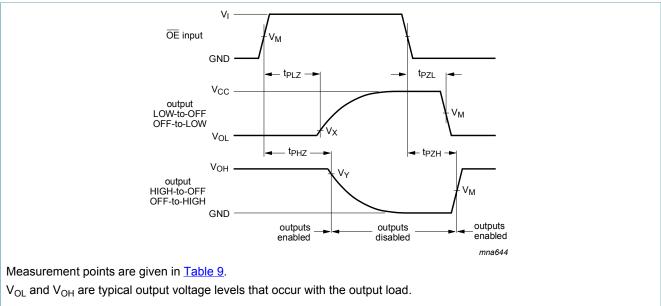
## 11.1 Waveforms and test circuit



Measurement points are given in Table 9.

 $V_{\text{OL}}$  and  $V_{\text{OH}}$  are typical output voltage levels that occur with the output load.

#### Figure 8. Input A to output Y propagation delay times

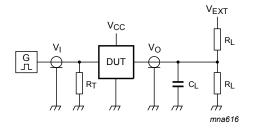


#### Figure 9. 3-state enable and disable times

#### Table 9. Measurement points

Supply voltage	Input	Output	Output				
V <sub>cc</sub>	V <sub>M</sub>	V <sub>M</sub>	V <sub>X</sub>	V <sub>Y</sub>			
1.65 V to 1.95 V	0.5V <sub>CC</sub>	0.5V <sub>CC</sub>	V <sub>OL</sub> + 0.15 V	V <sub>OH</sub> - 0.15 V			
2.3 V to 2.7 V	0.5V <sub>CC</sub>	0.5V <sub>CC</sub>	V <sub>OL</sub> + 0.15 V	V <sub>OH</sub> - 0.15 V			
2.7 V	1.5 V	1.5 V	V <sub>OL</sub> + 0.3 V	V <sub>OH</sub> - 0.3 V			
3.0 V to 3.6 V	1.5 V	1.5 V	V <sub>OL</sub> + 0.3 V	V <sub>OH</sub> - 0.3 V			
4.5 V to 5.5 V	0.5V <sub>CC</sub>	0.5V <sub>CC</sub>	V <sub>OL</sub> + 0.3 V	V <sub>OH</sub> - 0.3 V			

### Bus buffer/line driver; 3-state



Test data is given in Table 10.

Definitions for test circuit:

R<sub>L</sub> = Load resistance.

 $C_L$  = Load capacitance including jig and probe capacitance.

 $R_T$  = Termination resistance should be equal to the output impedance  $Z_o$  of the pulse generator.

 $V_{EXT}$  = External voltage for measuring switching times.

#### Figure 10. Test circuit for measuring switching times

#### Table 10. Test data

Supply voltage	Input	Input		Load		V <sub>EXT</sub>		
V <sub>cc</sub>	VI	t <sub>r</sub> , t <sub>f</sub>	CL	RL	t <sub>PLH</sub> , t <sub>PHL</sub>	t <sub>PZH</sub> , t <sub>PHZ</sub>	t <sub>PZL</sub> , t <sub>PLZ</sub>	
1.65 V to 1.95 V	V <sub>CC</sub>	≤ 2.0 ns	30 pF	1 kΩ	open	GND	2V <sub>CC</sub>	
2.3 V to 2.7 V	V <sub>CC</sub>	≤ 2.0 ns	30 pF	500 Ω	open	GND	2V <sub>CC</sub>	
2.7 V	2.7 V	≤ 2.5 ns	50 pF	500 Ω	open	GND	6 V	
3.0 V to 3.6 V	2.7 V	≤ 2.5 ns	50 pF	500 Ω	open	GND	6 V	
4.5 V to 5.5 V	V <sub>CC</sub>	≤ 2.5 ns	50 pF	500 Ω	open	GND	2V <sub>CC</sub>	

Bus buffer/line driver; 3-state

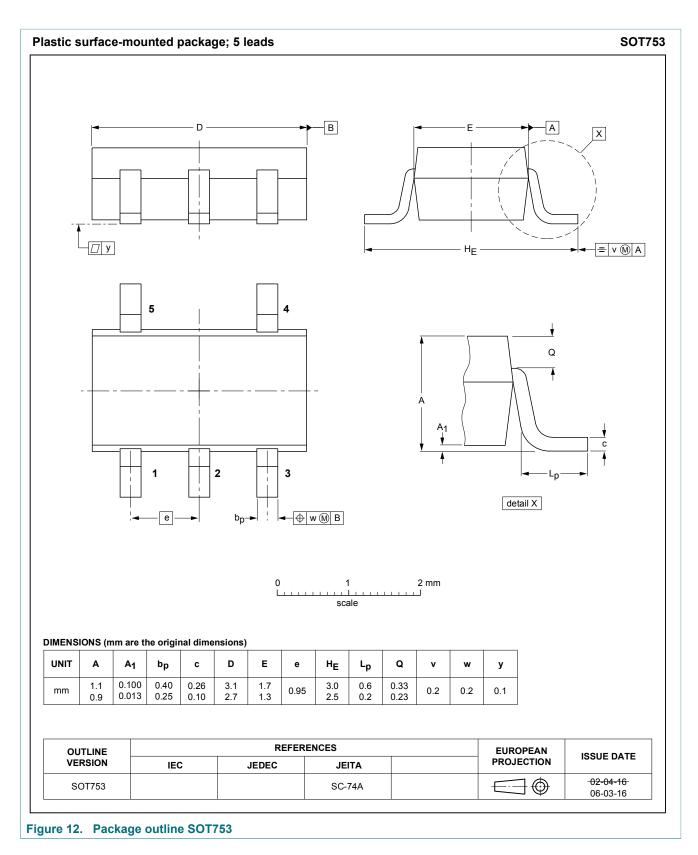
## 12 Package outline

	. pias		in shr	INK Sr		utline	раска	age; 5	iead	s; boo	dy wic	lth 1.2	5 mn	n			50	DT353
		Ť	- <u> </u>	— D -					с	¥ A		E		X	] () A			
		4		- z		4					A <sub>1</sub>		Lp	(A <sub>3</sub> )	Α Α 4 θ			
			1 ∐ →	e   e_1	▶    _    _	3 • ⊕ w	v 🕅					detail	€ ↓÷					
IMENS	IONS (n	ım are	1 Щ →	[e <sub>1</sub> ]	0 L	<b>€</b> -⊕ w	1.5 			3 mm		detail	€ ↓÷					
	IONS (n A max.	1m are A1	the orig	[e <sub>1</sub> ]	0 L	- ⊕ w s) c	1.5 sca	E <sup>(1)</sup>	e	3 mm	HE	detail	€ ↓÷	v	w	У	Z <sup>(1)</sup>	θ
DIMENS UNIT mm	Α			jinal din	0 L nension	⊕ w _ s)	1.5 sca	le	<b>e</b> 0.65		Н <sub>Е</sub> 2.25 2.0		× L •	0.2	<b>w</b> 0.1	<b>y</b> 0.1	<b>Z(1)</b> 0.60 0.15	θ 7° 0°
UNIT mm lote	A max. 1.1	<b>A<sub>1</sub></b> 0.1 0	<b>A</b> <sub>2</sub> 1.0 0.8	jinal din A3 0.15	0 <b>b</b> p 0.30 0.15	<ul> <li>- ⊕ w</li> <li>s)</li> <li>c</li> <li>0.25</li> <li>0.08</li> </ul>	1.5 sca D(1) 2.25 1.85	E(1) 1.35 1.15	0.65	e <sub>1</sub>	2.25	L	L → X	0.2			0.60	7°
UNIT mm lote . Plastic	A max. 1.1	<b>A<sub>1</sub></b> 0.1 0	<b>A</b> <sub>2</sub> 1.0 0.8	jinal din A3 0.15	0 <b>b</b> p 0.30 0.15	<ul> <li>- ⊕ w</li> <li>s)</li> <li>c</li> <li>0.25</li> <li>0.08</li> </ul>	1.5 sca D(1) 2.25 1.85	E(1) 1.35 1.15	0.65 cluded.	e <sub>1</sub>	2.25	L	L → X	0.3	0.1	0.1	0.60 0.15	7° 0°
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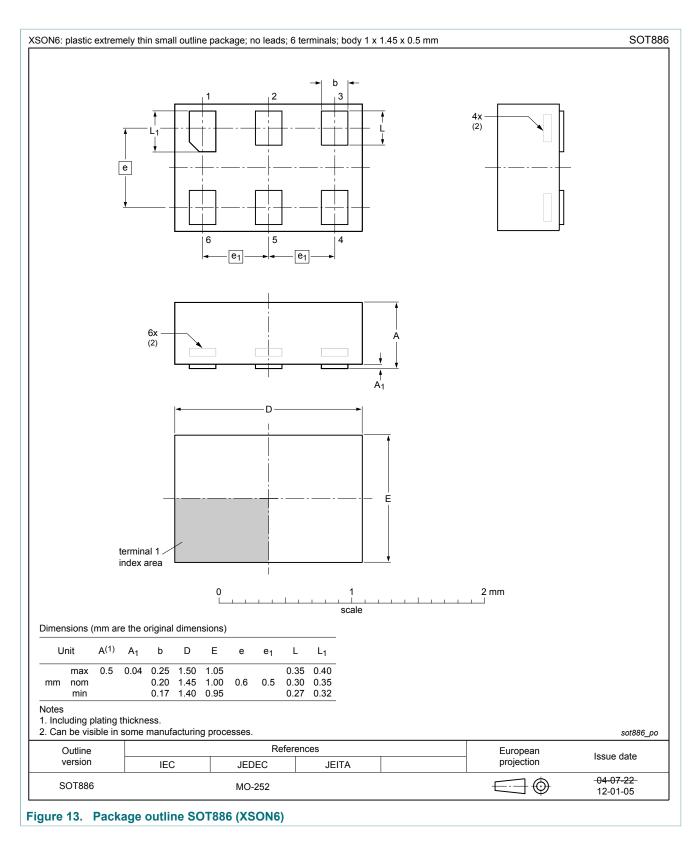
#### Figure 11. Package outline SOT353-1 (TSSOP5)

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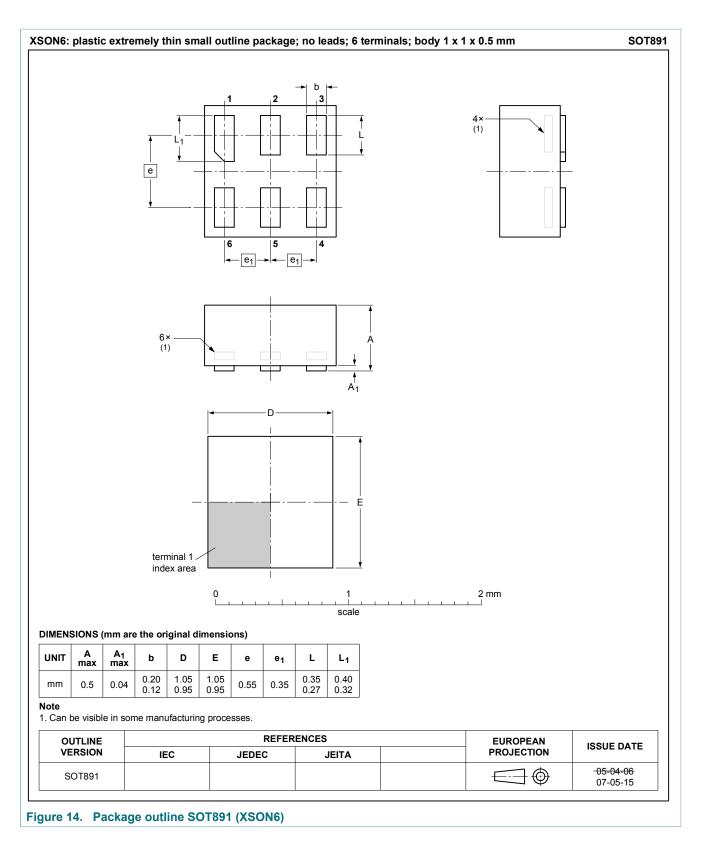
### Bus buffer/line driver; 3-state



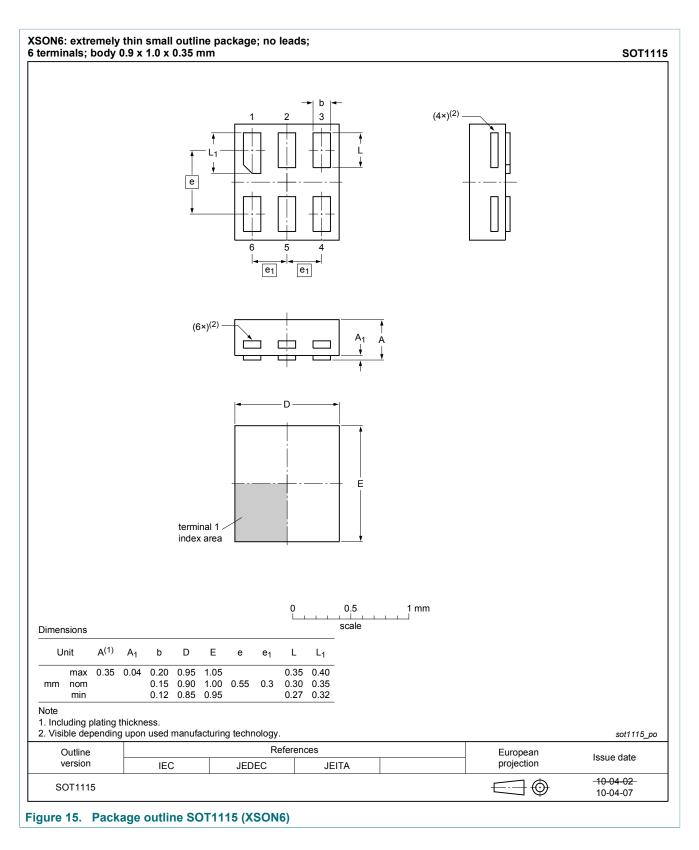
### Bus buffer/line driver; 3-state



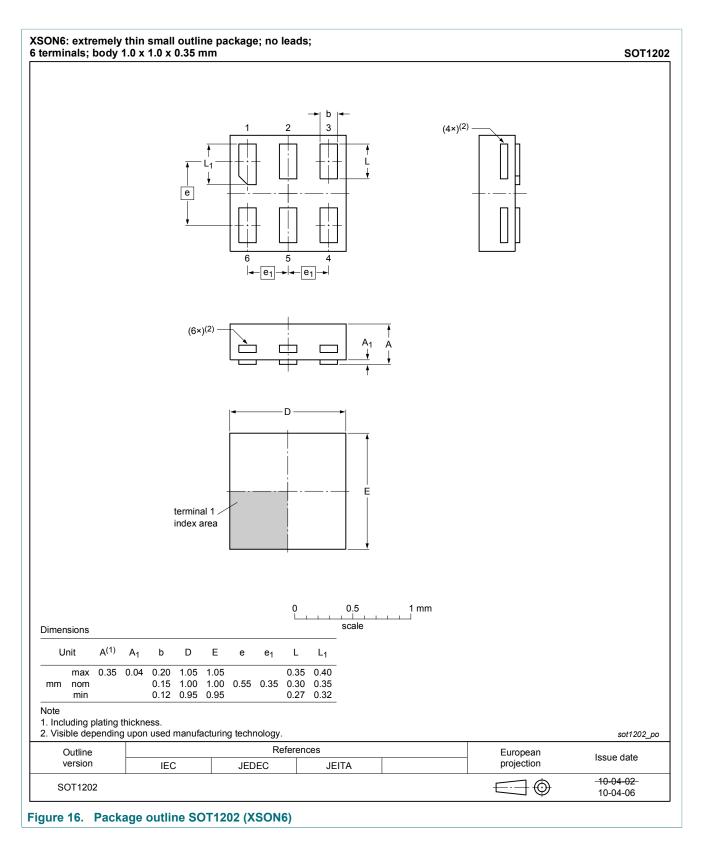
### Bus buffer/line driver; 3-state



### Bus buffer/line driver; 3-state



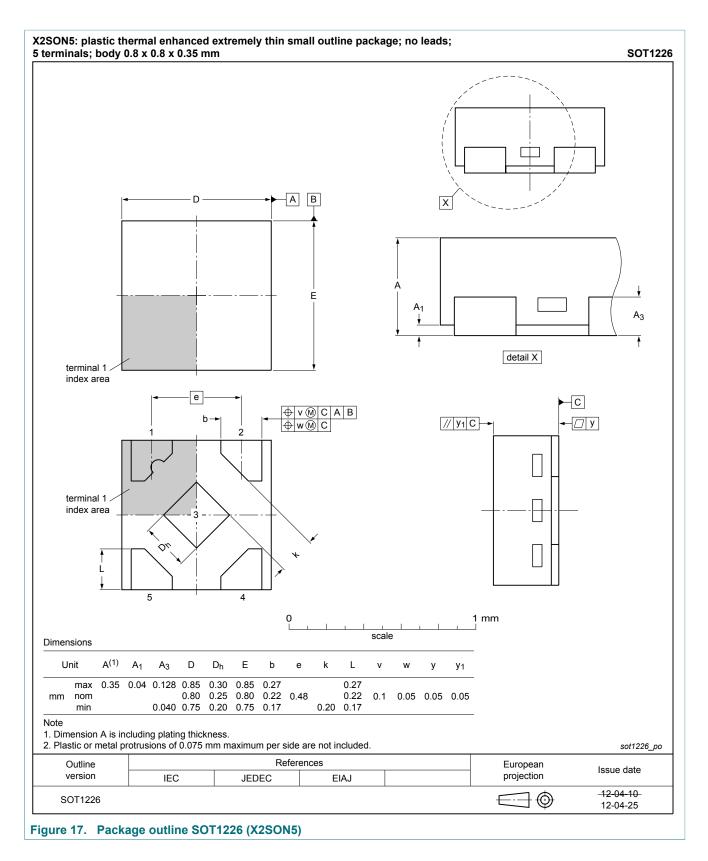
#### Bus buffer/line driver; 3-state



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#### Bus buffer/line driver; 3-state



## **13 Abbreviations**

Table 11. Abbreviations						
Acronym	Description					
CMOS	Complementary Metal Oxide Semiconductor					
DUT	Device Under Test					
ESD	ElectroStatic Discharge					
НВМ	Human Body Model					
MM	Machine Model					
TTL	Transistor-Transistor Logic					

## 14 Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
74LVC1G125 v.13	20171107	Product data sheet	-	74LVC1G125 v.12
Modifications:	Nexperia.	his data sheet has been rede re been adapted to the new o	• • • •	
74LVC1G125 v.12	20161202	Product data sheet	-	74LVC1G125 v.11
Modifications:	• <u>Table 7</u> : The m	aximum limits for leakage cu	urrent and supply curre	ent have changed.
74LVC1G125 v.11	20120702	Product data sheet	-	74LVC1G125 v.10
Modifications:	51	mber 74LVC1G125GX (SOT e drawing of SOT886 ( <mark>Figur</mark>	,	
74LVC1G125 v.10	20111207	Product data sheet	-	74LVC1G125 v.9
Modifications:	<ul> <li>Legal pages up</li> </ul>	odated.		
74LVC1G125 v.9	20101229	Product data sheet	-	74LVC1G125 v.8
74LVC1G125 v.8	20100824	Product data sheet	-	74LVC1G125 v.7
74LVC1G125 v.7	20070830	Product data sheet	-	74LVC1G125 v.6
74LVC1G125 v.6	20060912	Product data sheet	-	74LVC1G125 v.5
74LVC1G125 v.5	20040915	Product specification	-	74LVC1G125 v.4
74LVC1G125 v.4	20021118	Product specification	-	74LVC1G125 v.3
74LVC1G125 v.3	20020528	Product specification	-	74LVC1G125 v.2
74LVC1G125 v.2	20010406	Product specification	-	74LVC1G125 v.1
74LVC1G125 v.1	20001222	Product specification	-	-

## 15 Legal information

### 15.1 Data sheet status

Document status <sup>[1][2]</sup>	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

Please consult the most recently issued document before initiating or completing a design. [1]

The term 'short data sheet' is explained in section "Definitions".

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## 74LVC1G125

Bus buffer/line driver; 3-state

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